Hindawi Advances in Materials Science and Engineering Volume 2023, Article ID 9804082, 1 page https://doi.org/10.1155/2023/9804082



Retraction

Retracted: Investigation on V_2O_5 Thin Films for Field Effect Transistor Applications

Advances in Materials Science and Engineering

Received 26 December 2023; Accepted 26 December 2023; Published 29 December 2023

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This article has been retracted by Hindawi, as publisher, following an investigation undertaken by the publisher [1]. This investigation has uncovered evidence of systematic manipulation of the publication and peer-review process. We cannot, therefore, vouch for the reliability or integrity of this article.

Please note that this notice is intended solely to alert readers that the peer-review process of this article has been compromised.

Wiley and Hindawi regret that the usual quality checks did not identify these issues before publication and have since put additional measures in place to safeguard research integrity.

We wish to credit our Research Integrity and Research Publishing teams and anonymous and named external researchers and research integrity experts for contributing to this investigation.

The corresponding author, as the representative of all authors, has been given the opportunity to register their agreement or disagreement to this retraction. We have kept a record of any response received.

References

[1] S. K. Suresh Babu, D. Jackuline Moni, D. Gracia, and A. G. Adigo, "Investigation on V₂O₅ Thin Films for Field Effect Transistor Applications," *Advances in Materials Science and Engineering*, vol. 2021, Article ID 2414589, 7 pages, 2021.